TOSHIBA Insulated Gate Bipolar Transistor Silicon N Channel IGBT

# GT8G136

## Strobe Flash Applications

- Compact and Thin (TSSOP-8) package
- Enhancement-mode
- Peak collector current: Ic = 150 A (max)

 $(@V_{GE}=3.0V(min),Ta=70^{\circ}C(max))/$ 

# Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	400	V	
Gate-emitter voltage	DC	$V_{GES}$	± 6	V	
	Pulse	$V_{GES}$	± 8		
Collector current	Pulse (Note 1)	I <sub>CP</sub>	150	Α	
Collector power dissipation (t=10 s)	(Note 2a)	P <sub>C</sub> (1)	1.1	W	
	(Note 2b)	P <sub>C</sub> (2)	0.6	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Rating	Unit	
Thermal resistance , junction to ambient (t = 10 s) (Note2a)	R <sub>th (j-a)</sub> (1)	114	°C/W	
Thermal resistance , junction to ambient (t = 10 s) (Note2b)	R <sub>th (j-a)</sub> (2)	208	°C/W	

## Marking (Note 3)

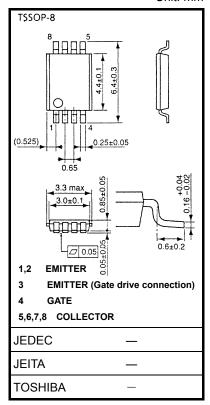
Note: For (Note 1), (Note 2a), (Note 2b) and (Note 3), Please refer to the next page.

Part No. (or abbreviation code)

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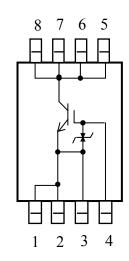
A line indicates lead (Pb)-free package or lead (Pb)-free finish.

Unit: mm



Weight: 0.035 g (typ.)

## **Circuit Configuration**



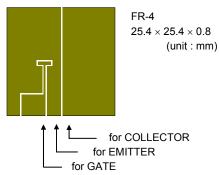
# **Electrical Characteristics (Ta = 25°C)**

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	$V_{GE} = \pm 6 \text{ V}, V_{CE} = 0$	_	_	± 10	μА
Collector cut-off current		I <sub>CES</sub>	V <sub>CE</sub> = 400 V, V <sub>GE</sub> = 0	_	_	10	μΑ
Gate-emitter cut-off voltage		V <sub>GE</sub> (OFF)	I <sub>C</sub> = 1 mA, V <sub>CE</sub> = 5 V	0.65	1.0	1.35	٧
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 150 A, V <sub>GE</sub> = 3 V		3.5		>
Input capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10 V, V <sub>GE</sub> = 0, f = 1 MHz		2500		pF
Switching time	Rise time	t <sub>r</sub>	$\begin{array}{c} 3 \ \text{V} \\ 0 \\ \hline \\ \text{V}_{\text{IN}} : \ t_r \leq 100 \ \text{ns} \\ \text{t}_f \leq 100 \ \text{ns} \\ \hline \\ \text{Duty cycle} \leq 1\% \\ \end{array} \begin{array}{c} 51 \ \Omega \\ \hline \\ \approx 300 \ \text{V} \\ \hline \end{array}$	_	1.5	_	- µs
	Turn-on time	t <sub>on</sub>			1.7		
	Fall time	t <sub>f</sub>			1.6		
	Turn-off time	t <sub>off</sub>			1.9		

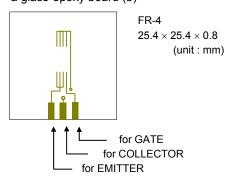
#### Note

Note 1: Please use devices on condition that the junction temperature is below 150°C. Repetitive rating: pulse width limited by maximum junction temperature.

Note 2a : Device mounted on a glass-epoxy board (a)



Note 2b : Device mounted on a glass-epoxy board (b)



Note 3: O on lower right of the marking indicates Pin 1.



Pb-Free Finish (Only a coating lead terminal):

It is marking about an underline to a week of manufacture mark.



# Caution on handling

This device is MOS gate type. Therefore, please care of a protection from ESD in your handling.

# Caution in design

You should be design dV/dt value under lcp=150A is below 400 V/ $\mu$ s when IGBT turn off under Ta=70°C . You should be design to don't flow collector current through terminal number 3 .

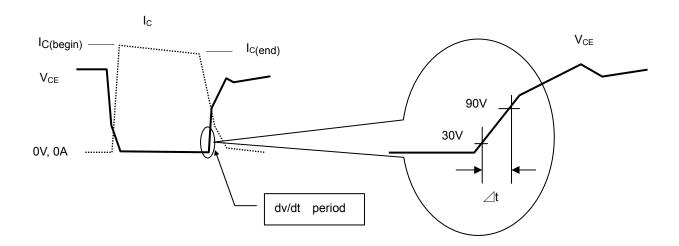
#### definition of dv/dt

The slope of V<sub>CE</sub> from 30v to 90v (attached figure.1)

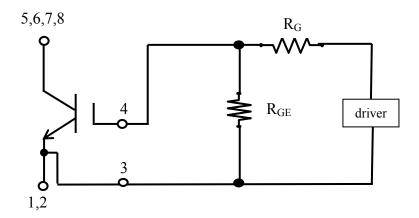
$$dv/dt = (90V-30V) / (\triangle t)$$
$$= 60V / \triangle t$$

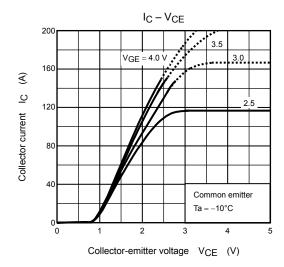
waveform

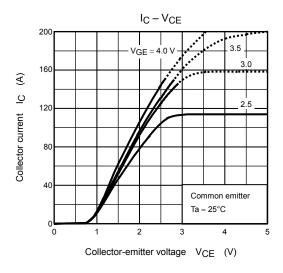
waveform (expansion)

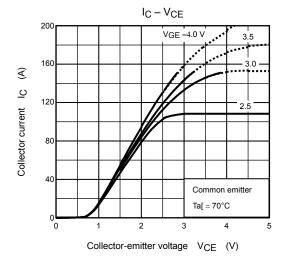


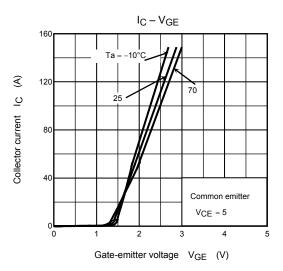
Gate drive connection

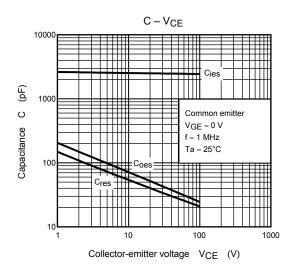


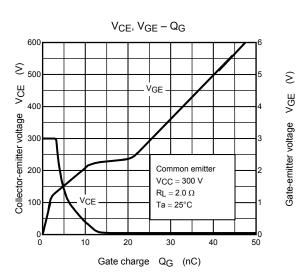


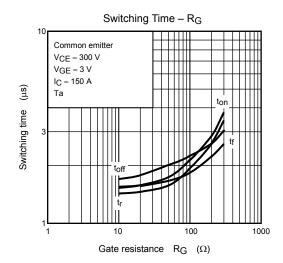


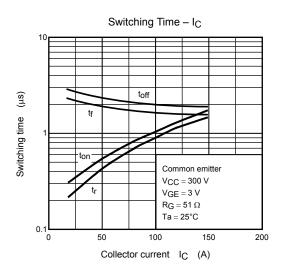


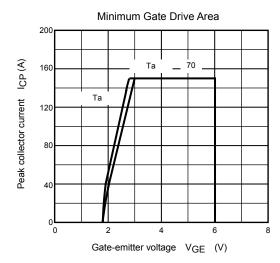


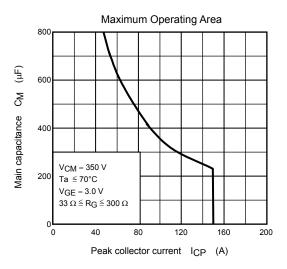












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